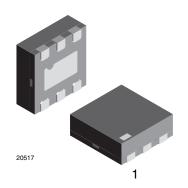


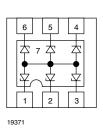
6-Line ESD-Protection Diode Array in LLP75

Features

- Ultra compact LLP75-7L package
- 6-line ESD-protection
- Low leakage current $I_R < 1 \mu A$
- Low load capacitance C_D = 40 pF
- ESD-immunity acc. IEC 61000-4-2
 ± 30 kV contact discharge
 - ± 30 kV air discharge
- Working voltage range V_{RWM} = 5 V
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC







Marking (example only)



Dot = Pin 1 marking XX = Date code

YY = Type code (see table below)

Ordering Information

Device name	Device name Ordering code		Minimum order quantity		
VESD05A6-HAF VESD05A6-HAF-GS		3000	15000		

Package Data

Device name	Package name	Type code	Weight	Molding t compound Moisture sensitivity level Sold flammability rating		Soldering conditions
VESD05A6-HAF	LLP75-7L	AS	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

^{*} Please see document "Vishay Green and Halogen-Free Definitions (5-2008)" http://www.vishay.com/doc?99902

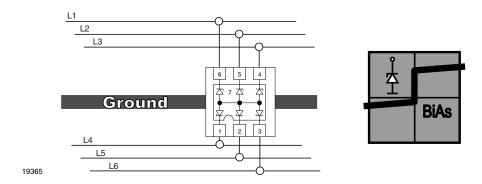


Absolute Maximum Ratings

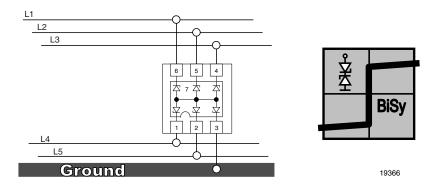
Rating	Test condition			Value	Unit
Peak pulse current	BiAs-Mode: each input (pin 1 to pin 6) to ground (pin acc. IEC 61000-4-5; t_p = 8/20 μ s; single shot	I _{PPM}	5	Α	
Peak pulse power	BiAs-mode: each input (pin 1 to pin 6) to ground (pin 2); acc. IEC 61000-4-5; $t_p = 8/20 \mu s$; single shot			60	W
ESD immunity	Acc. IEC61000-4-2; 10 pulses BiAs-mode: each input (pin 1 to pin 6) to ground (pin 2)	Contact discharge	V _{ESD}	± 30	kV
		Air discharge	V _{ESD}	± 30	kV
Operating temperature	Junction temperature			- 40 to + 125	°C
Storage temperature		•	T _{STG}	- 55 to + 150	°C

Application Note:

a) With the **VESD05A6-HAF** 6 different signal or data lines can be clamped to ground. Due to the different clamping levels in forward and reverse direction the **VESD05A6-HAF** clamping behavior is <u>Bi</u>directional and <u>Asymmetrical</u> (BiAs).



b) If symmetrical clamping behaviour is required the **VESD05A6-HAF** can also be used as a <u>Bi</u>directional <u>Sy</u>mmetrical protection device protecting up to 5 lines. In this case pin 7 must not be connected.





Electrical Characteristics

Ratings at 25 °C, ambient temperature unless otherwise specified

VESD05A6-HAF

BiAs mode (between pin 1, 2, 3, 4, 5 or 6 and pin 7)

Parameter	Test conditions/remarks	Symbol	Min.	Тур.	Max.	Unit
Protection paths	Number of lines which can be protected	N _{lines}			6	lines
Reverse stand off voltage	at I _R = 1 μA	V _{RWM}	5			V
Max. reverse current	at V _R = 5 V	I _R		< 0.1	1	μΑ
Reverse break down voltage	at I _R = 1 mA	V_{BR}	6	6.6	7.5	V
Reverse clamping voltage	at I _{PP} = 1 A	V _C		8.1	10	V
	at I _{PP} = I _{PPM} = 5 A	V _C		11.3	12	V
Forward clamping voltage	at I _{PP} = 1 A	V _F		1.5	1.8	V
	at I _{PP} = I _{PPM} = 5 A	V _F		3.2	4.5	V
Line capacitance	at $V_R = 0 V$; $f = 1 MHz$	C _D		40	50	pF
	at V _R = 2.5 V; f = 1 MHz	C _D		24		pF

Typical Characteristics T_{amb} = 25 °C, unless otherwise specified

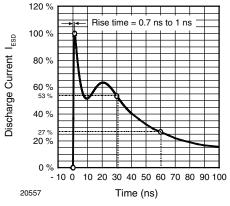


Figure 1. ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

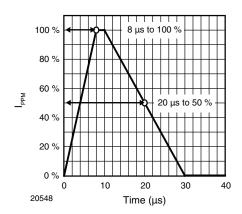


Figure 2. 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5



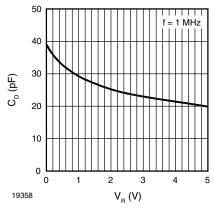


Figure 3. Typical Capacitance C_D vs. Reverse Voltage V_R

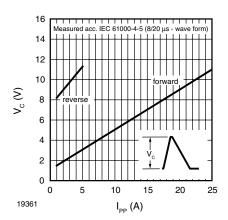


Figure 6. Typical Clamping Voltage vs. Peak Pulse Current IPP

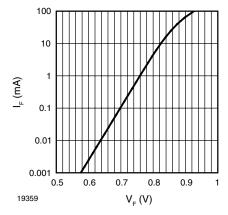


Figure 4. Typical Forward Current I_F vs. Forward Voltage V_F

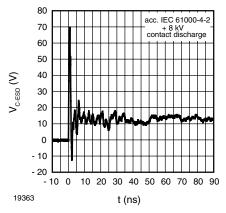


Figure 7. Typical Clamping Performance on + 8 kV - ESD Events (acc. IEC 61000-4-2)

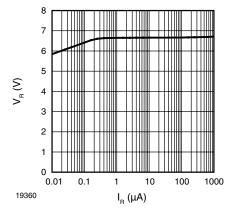


Figure 5. Typical Reverse Voltage $V_{\mbox{\scriptsize R}}$ vs. Reverse Current $I_{\mbox{\scriptsize R}}$

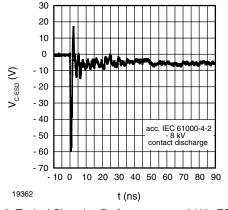


Figure 8. Typical Clamping Performance on - 8 kV - ESD Events (acc. IEC 61000-4-2)



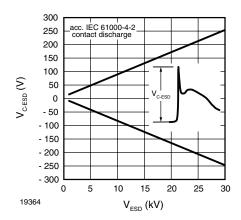
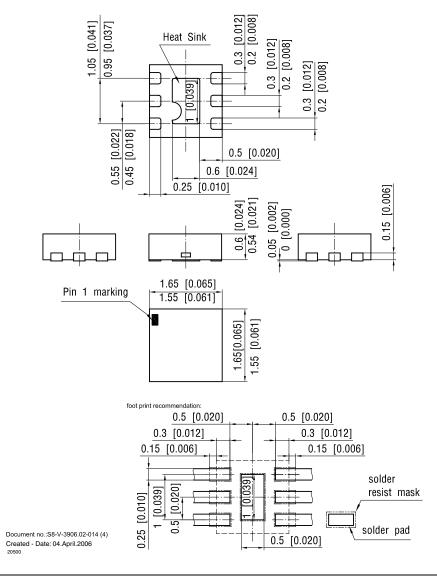


Figure 9. Typical max. Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

Package Dimensions in millimeters (inches): LLP75-7L



VESD05A6-HAF

Vishay Semiconductors



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

Document Number 81311

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Vishay

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